SCES614C-OCTOBER 2004-REVISED JUNE 2006

FEATURES

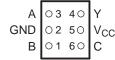
- Available in the Texas Instruments
 NanoStar™ and NanoFree™ Packages
- Single-Supply Voltage Translator
- 1.8 V to 3.3 V (at V_{CC} = 3.3 V)
- 2.5 V to 3.3 V (at V_{CC} = 3.3 V)
- 1.8 V to 2.5 V (at V_{CC} = 2.5 V)
- 3.3 V to 2.5 V (at V_{CC} = 2.5 V)
- Nine Configurable Gate Logic Functions
- Schmitt-Trigger Inputs Reject Input Noise and Provide Better Output Signal Integrity
- I_{off} Supports Partial-Power-Down Mode With Low Leakage Current (0.5 μA)

DBV OR DCK PACKAGE (TOP VIEW)

B 1 6 C
GND 2 5 V_{CC}

- Very Low Static and Dynamic Power Consumption
- Pb-Free Packages Available: SOT-23 (DBV), SC-70 (DCK), and WCSP (NanoFree)
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- ESD Performance Tested Per JESD 22
 - 2000-V Human-Body Model (A114-B, Class II)
 - 200-V Machine Model (A115-A)
 - 1000-V Charged-Device Model (C101)
- Related Devices: SN74AUP1T97, SN74AUP1T57, and SN74AUP1T58

YZP PACKAGE (BOTTOM VIEW)



DESCRIPTION/ORDERING INFORMATION

AUP technology is the industry's lowest-power logic technology designed for use in battery-operated or battery backed-up equipment. The SN74AUP1T98 is designed for logic-level translation applications with input switching levels that accept 1.8-V LVCMOS signals, while operating from either a single 3.3-V or 2.5-V V_{CC} supply.

The wide V_{CC} range of 2.3 V to 3.6 V allows the possibility of battery voltage drop during system operation and ensures normal operation between this range.

Schmitt-trigger inputs ($\Delta V_T = 210 \text{ mV}$ between positive and negative input transitions) offer improved noise immunity during switching transitions, which is especially useful on analog mixed-mode designs. Schmitt-trigger inputs reject input noise, ensure integrity of output signals, and allow for slow input signal transition.

The SN74AUP1T98 can be easily configured to perform a required gate function by connecting A, B, and C inputs to V_{CC} or ground (see Function Selection table). Up to nine commonly used logic gate functions can be performed.

 I_{off} is a feature that allows for powered-down conditions ($V_{\text{CC}} = 0 \text{ V}$) and is important in portable and mobile applications. When $V_{\text{CC}} = 0 \text{ V}$, signals in the range from 0 V to 3.6 V can be applied to the inputs and outputs of the device. No damage occurs to the device under these conditions.

The SN74AUP1T98 is designed with optimized current-drive capability of 4 mA to reduce line reflections, overshoot, and undershoot caused by high-drive outputs.

Nanostar[™] and Nanofree[™] package technology is a major breakthrough in IC packaging concepts, using the die as the package.

Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

NanoStar, NanoFree are trademarks of Texas Instruments.



ORDERING INFORMATION

T _A	PACKAGE ⁽¹⁾		ORDERABLE PART NUMBER	TOP-SIDE MARKING(2)
-40°C to 85°C	NanoFree [™] – WCSP (DSBGA) 0.23-mm Large Bump – YZP (Pb-free)	Tape and reel	SN74AUP1T98YZPR	TK_
	SOT (SOT-23) – DBV	Tape and reel	SN74AUP1T98DBVR	HT6_
	SOT (SC-70) - DCK	Tape and reel	SN74AUP1T98DCKR	TK_

- Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.
- (2) DBV/DCK: The actual top-side marking has one additional character that designates the assembly/test site. YZP: The actual top-side marking has three preceding characters to denote year, month, and sequence code, and one following character to designate the assembly/test site. Pin 1 identifier indicates solder-bump composition (1 = SnPb, = Pb-free).

FUNCTION SELECTION TABLE

LOGIC FUNCTION	FIGURE NO.
2-to-1 data selector	5
2-input AND gate	6
2-input OR gate with one inverted input	7
2-input NAND gate with one inverted input	7
2-input AND gate with one inverted input	8
2-input NOR gate with one inverted input	8
2-input OR gate	9
Inverter	10
Noninverted buffer	11

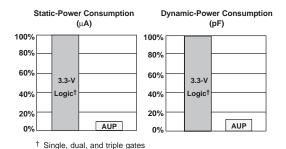


Figure 1. AUP - The Lowest-Power Family

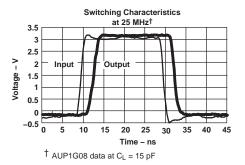


Figure 2. Excellent Signal Integrity

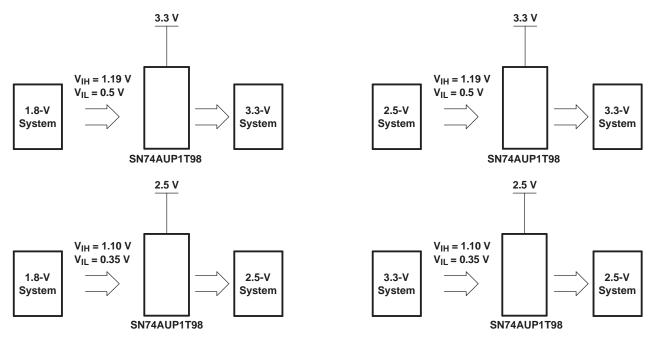


Figure 3. Possible Voltage-Translation Combinations

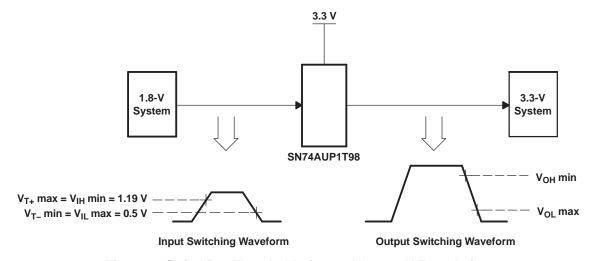


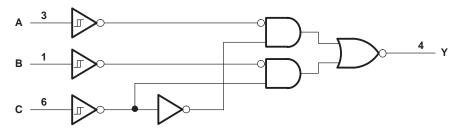
Figure 4. Switching Thresholds for 1.8-V to 3.3-V Translation



FUNCTION TABLE

	INPUTS		OUTPUT
С	В	Α	Υ
L	L	L	Н
L	L	Н	Н
L	Н	L	L
L	Н	Н	L
Н	L	L	Н
Н	L	Н	L
Н	Н	L	Н
Н	Н	Н	L

LOGIC DIAGRAM (POSITIVE LOGIC)





LOGIC CONFIGURATIONS

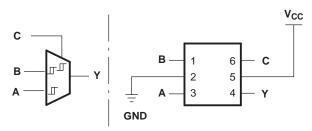


Figure 5. 157+04: 2-to-1 Data Selector With Inverted Output When C is L, Y = $\overline{\underline{B}}$ When C is H, Y = $\overline{\overline{A}}$

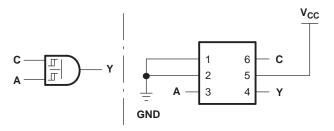


Figure 6. 00: 2-Input NAND Gate

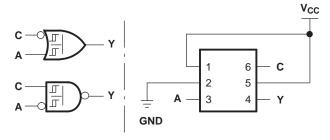


Figure 7. 14+02/14+08: 2-Input NOR Gate With One Inverted Input 2-Input AND Gate With One Inverted Input

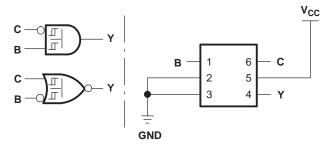


Figure 8. 14+00/14+32: 2-Input NAND Gate With One Inverted Input 2-Input OR Gate With One Inverted Input



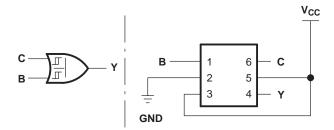


Figure 9. 32: 2-Input NOR Gate

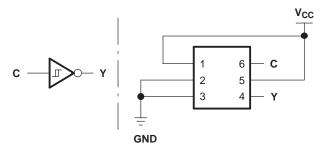


Figure 10. 17/34: Noninverted Buffer

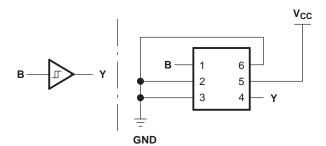


Figure 11. 04/14: Inverter



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Absolute Maximum Ratings(1)

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
V_{CC}	Supply voltage range		-0.5	4.6	V
VI	Input voltage range (2)		-0.5	4.6	V
Vo	Voltage range applied to any output in the hi	igh-impedance or power-off state (2)	-0.5	4.6	V
Vo	Output voltage range in the high or low state	9(2)	-0.5	V _{CC} + 0.5	V
I_{IK}	Input clamp current	V ₁ < 0		-50	mA
I _{OK}	Output clamp current	V _O < 0		-50	mA
Io	Continuous output current			±20	mA
	Continuous current through V _{CC} or GND			±50	mA
		DBV package		165	
θ_{JA}	Package thermal impedance (3)	DCK package		259	°C/W
		YZP package		123	
T _{stg}	Storage temperature range		-65	150	°C

⁽¹⁾ Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) The input negative-voltage and output voltage ratings may be exceeded if the input and output current ratings are observed.

Recommended Operating Conditions(1)

			MIN	MAX	UNIT
V _{CC}	Supply voltage		2.3	3.6	V
V _I	Input voltage		0	3.6	V
Vo	Output voltage		0	V _{CC}	V
	High level output output	V _{CC} = 2.3 V		-3.1	A
I _{OH}	High-level output current	$V_{CC} = 3 V$		-4	mA
	Lour lovel output ourrent	V _{CC} = 2.3 V		3.1	A
I _{OL} LO	Low-level output current	V _{CC} = 3 V		4	mA
T _A	Operating free-air temperature		-40	85	°C

⁽¹⁾ All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.

⁽³⁾ The package thermal impedance is calculated in accordance with JESD 51-7.

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Electrical Characteristics

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	V _{CC}	T _A =	25°C	T _A = -40 to 85°0)°C C	UNIT
			MIN	TYP MAX	MIN	MAX	
V _{T+}		2.3 V to 2.7 V	0.6	1.1	0.6	1.1	
Positive-going input threshold voltage		3 V to 3.6 V	0.75	1.16	0.75	1.19	V
V _{T-}		2.3 V to 2.7 V	0.35	0.6	0.35	0.6	
Negative-going input threshold voltage		3 V to 3.6 V	0.5	0.85	0.5	0.85	V
ΔV_{T}		2.3 V to 2.7 V	0.23	0.6	0.1	0.6	
Hysteresis (V _{T+} - V _{T-})		3 V to 3.6 V	0.25	0.56	0.15	0.56	V
	I _{OH} = -20 μA	2.3 V to 3.6 V	V _{CC} - 0.1		V _{CC} - 0.1		
	$I_{OH} = -2.3 \text{ mA}$	0.01/	2.05		1.97		V
V_{OH}	I _{OH} = -3.1 mA	2.3 V	1.9		1.85		
	$I_{OH} = -2.7 \text{ mA}$	3 V	2.72		2.67		
	$I_{OH} = -4 \text{ mA}$	3 V	2.6		2.55		
	$I_{OL} = 20 \mu A$	2.3 V to 3.6 V		0.1		0.1	
	$I_{OL} = 2.3 \text{ mA}$	2.3 V		0.31		0.33	V
V_{OL}	I _{OL} = 3.1 mA	2.3 V		0.44		0.45	
	I _{OL} = 2.7 mA	3 V		0.31		0.33	
	I _{OL} = 4 mA	3 V		0.44		0.45	
I _I All inputs	$V_I = 3.6 \text{ V or GND}$	0 V to 3.6 V		0.1		0.5	μΑ
$I_{\rm off}$	V_I or $V_O = 0$ V to 3.6 V	0 V		0.1		0.5	μΑ
Δl_{off}	V_I or $V_O = 3.6 \text{ V}$	0 V to 0.2 V		0.2		0.5	μΑ
I_{CC}	$V_I = 3.6 \text{ V or GND}, I_O = 0$	2.3 V to 3.6 V		0.5		0.9	μΑ
	One input at 0.3 V or 1.1 V, Other inputs at 0 or V_{CC} , $I_{O} = 0$	2.3 V to 2.7 V				4	μА
Δl _{CC}	One input at 0.45 V or 1.2 V, Other inputs at 0 or V_{CC} , $I_{O} = 0$	3 V to 3.6 V				12	μΛ
C_{i}	$V_I = V_{CC}$ or GND	3.3 V		1.5			pF
C _o	$V_O = V_{CC}$ or GND	3.3 V		3			pF

Switching Characteristics

over recommended operating free-air temperature range, V_{CC} = 2.5 V \pm 0.2 V, V_I = 1.8 V \pm 0.15 V (unless otherwise noted) (see Figure 12)

PARAMETER	FROM	TO (OUTDUT)	CL	T _A = 25°C			T _A = -	UNIT	
	(INPUT)	(OUTPUT)	_	MIN	TYP	MAX	MIN	MAX	
		V	5 pF	1.8	2.3	2.9	0.5	6.8	ns
	A D or C		10 pF	2.3	2.8	3.4	1	7.9	
^L pd	A, B, or C	Ť	15 pF	2.6	3.1	.1 3.8	1	8.7	
			30 pF	3.8	4.4	5.1	1.5	10.8	

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Switching Characteristics

over recommended operating free-air temperature range, V_{CC} = 2.5 V \pm 0.2 V, V_I = 2.5 V \pm 0.2 V (unless otherwise noted) (see Figure 12)

PARAMETER	FROM	TO (OUTPUT)	CL	T _A = 25°C			T _A = -	UNIT	
	(INPUT)	(OUTPUT)	_	MIN	TYP	MAX	MIN	MAX	
		V	5 pF	1.8	2.3	3.1	0.5	6	
	A P or C		10 pF	2.2	2.8	3.5	1	7.1	
^t pd	A, B, or C	Ť	15 pF	2.6	3.2	5.2	1	7.9	ns
			30 pF	3.7	4.4	5.2	1.5	10	

Switching Characteristics

over recommended operating free-air temperature range, V_{CC} = 2.5 V \pm 0.2 V, V_I = 3.3 V \pm 0.3 V (unless otherwise noted) (see Figure 12)

PARAMETER	FROM	TO (OUTPUT)	TO (OUTPUT) C _L	T _A = 25°C			T _A = -	UNIT					
	(INPUT)	(001F01)		MIN	TYP	MAX	MIN	MAX					
		Y	5 pF	2	2.7	3.5	0.5	5.5	-				
	A D or C		10 pF	2.4	3.1	3.9	1	6.5					
^L pd	A, B, or C		I	Ť	Y	Y	15 pF	2.8	3.5	4.3	1	7.4	ns
			30 pF	4	4.7	5.5	1.5	9.5					

Switching Characteristics

over recommended operating free-air temperature range, V_{CC} = 3.3 V \pm 0.3 V, V_I = 1.8 V \pm 0.15 V (unless otherwise noted) (see Figure 12)

PARAMETER	FROM	TO	CL	T _A = 25°C			T _A = -	UNIT				
	(INPUT)	(OUTPUT)	_	MIN	TYP	MAX	MIN	MAX	í			
		Y	5 pF	1.6	2	2.5	0.5	8	8.5			
	A D == C		10 pF	2	2.4	2.9	1	8.5				
t _{pd} A, B, or C	Y		Y	Y	Y	15 pF	2.3	2.8	3.3	1	9.1	ns
			30 pF	3.4	3.9	4.4	1.5	9.8				

Switching Characteristics

over recommended operating free-air temperature range, V_{CC} = 3.3 V \pm 0.3 V, V_I = 2.5 V \pm 0.2 V (unless otherwise noted) (see Figure 12)

PARAMETER	FROM	TO	CL	Т,	_A = 25°C		T _A = -	UNIT				
	(INPUT)	(OUTPUT)	_	MIN	TYP	MAX	MIN	MAX				
		Υ	5 pF	1.6	1.9	2.4	0.5	5.3				
	A D or C		Υ	Y	10 pF	2	2.3	2.7	1	6.1		
t _{pd} A, B, or C	r I				Y	Ť	.	15 pF	2.3	2.7	3.1	1
			30 pF	3.4	3.8	4.2	1.5	8.5				

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Switching Characteristics

over recommended operating free-air temperature range, V_{CC} = 3.3 V \pm 0.3 V, V_I = 3.3 V \pm 0.3 V (unless otherwise noted) (see Figure 12)

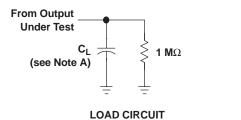
PARAMETER	FROM	TO (OUTPUT)	CL	T _A = 25°C			T _A = -	UNIT			
	(INPUT)	(OUTPUT)	_	MIN	TYP	MAX	MIN	MAX			
		Y	5 pF	1.6	2.1	2.7	0.5	4.7			
	A P or C		Υ	Υ	10 pF	2	2.4	3	1	5.7	no
t _{pd} A, B, or C	A, B, or C				'	15 pF	2.3	2.7	3.3	1	6.2
			30 pF	3.4	3.8	4.4	1.5	7.8			

Operating Characteristics

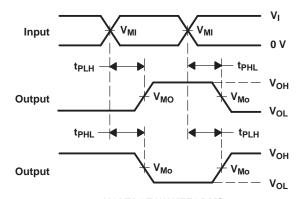
 $T_A = 25^{\circ}C$

PARAMETER		TEST CONDITIONS	V _{CC} = 2.5 V	$V_{CC} = 3.3 \text{ V}$	UNIT	
	FARAMETER	TEST CONDITIONS	TYP	TYP	ONIT	
C_{pd}	Power dissipation capacitance	f = 10 MHz	4	5	pF	

PARAMETER MEASUREMENT INFORMATION



	V _{CC} = 2.5 V ± 0.2 V	V_{CC} = 3.3 V \pm 0.3 V
C _L	5, 10, 15, 30 pF	5, 10, 15, 30 pF
V _{MI}	V _I /2	V _I /2
V _{MO}	V _{CC} /2	V _{CC} /2



VOLTAGE WAVEFORMS
PROPAGATION DELAY TIMES
INVERTING AND NONINVERTING OUTPUTS

NOTES: A. C_L includes probe and jig capacitance.

- B. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, $Z_0 = 50 \Omega$, slew rate \geq 1 V/ns.
- C. The outputs are measured one at a time, with one transition per measurement.
- D. t_{PLH} and t_{PHL} are the same as t_{pd} .

Figure 12. Load Circuit and Voltage Waveforms

PACKAGE OPTION ADDENDUM



com 29-May-2007

PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	e Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp ⁽³⁾
SN74AUP1T98DBVR	ACTIVE	SOT-23	DBV	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74AUP1T98DBVRE4	ACTIVE	SOT-23	DBV	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74AUP1T98DBVRG4	ACTIVE	SOT-23	DBV	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74AUP1T98DBVT	ACTIVE	SOT-23	DBV	6	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74AUP1T98DBVTE4	ACTIVE	SOT-23	DBV	6	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74AUP1T98DBVTG4	ACTIVE	SOT-23	DBV	6	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74AUP1T98DCKR	ACTIVE	SC70	DCK	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74AUP1T98DCKRE4	ACTIVE	SC70	DCK	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74AUP1T98DCKRG4	ACTIVE	SC70	DCK	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74AUP1T98DCKT	ACTIVE	SC70	DCK	6	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74AUP1T98DCKTE4	ACTIVE	SC70	DCK	6	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74AUP1T98DCKTG4	ACTIVE	SC70	DCK	6	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74AUP1T98YZPR	ACTIVE	WCSP	YZP	6	3000	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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PACKAGE OPTION ADDENDUM

29-May-2007

incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.



TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74AUP1T98DBVR	SOT-23	DBV	6	3000	180.0	9.2	3.23	3.17	1.37	4.0	8.0	Q3
SN74AUP1T98DBVT	SOT-23	DBV	6	250	180.0	9.2	3.23	3.17	1.37	4.0	8.0	Q3
SN74AUP1T98DCKR	SC70	DCK	6	3000	180.0	9.2	2.24	2.34	1.22	4.0	8.0	Q3
SN74AUP1T98DCKT	SC70	DCK	6	250	180.0	9.2	2.24	2.34	1.22	4.0	8.0	Q3





*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74AUP1T98DBVR	SOT-23	DBV	6	3000	202.0	201.0	28.0
SN74AUP1T98DBVT	SOT-23	DBV	6	250	202.0	201.0	28.0
SN74AUP1T98DCKR	SC70	DCK	6	3000	202.0	201.0	28.0
SN74AUP1T98DCKT	SC70	DCK	6	250	202.0	201.0	28.0

DBV (R-PDSO-G6)

PLASTIC SMALL-OUTLINE PACKAGE



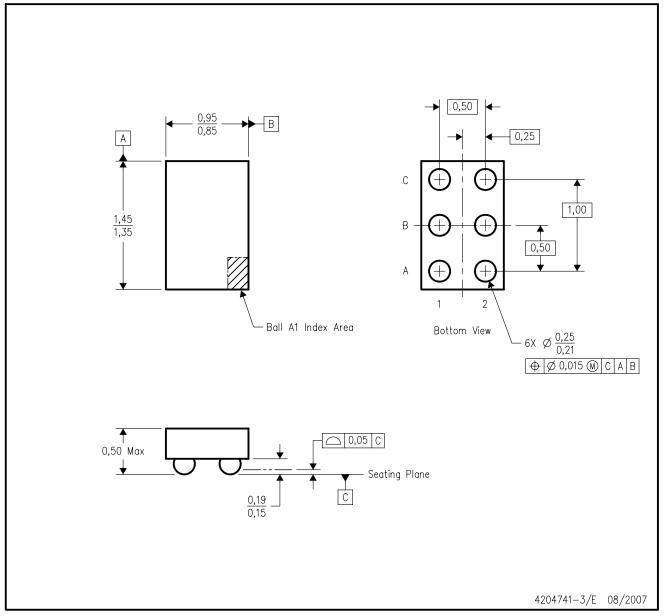
NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
- D. Leads 1,2,3 may be wider than leads 4,5,6 for package orientation.
- Falls within JEDEC MO-178 Variation AB, except minimum lead width.



YZP (R-XBGA-N6)

DIE-SIZE BALL GRID ARRAY



NOTES: A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.

- B. This drawing is subject to change without notice.
- C. NanoFree $^{\text{TM}}$ package configuration.
- D. This package is lead-free. Refer to the 6 YEP package (drawing 4204725) for tin-lead (SnPb).

NanoFree is a trademark of Texas Instruments.



DCK (R-PDSO-G6)

PLASTIC SMALL-OUTLINE PACKAGE



NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
- D. Falls within JEDEC MO-203 variation AB.



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